

# Single P-channel MOSFET

## ELM14443AA-N

### ■ General description

ELM14443AA-N uses advanced trench technology to provide excellent  $R_{ds(on)}$ , low gate charge and low gate resistance.

### ■ Features

- $V_{ds} = -40V$
- $I_d = -6.5A$  ( $V_{gs} = -10V$ )
- $R_{ds(on)} < 42m\Omega$  ( $V_{gs} = -10V$ )
- $R_{ds(on)} < 63m\Omega$  ( $V_{gs} = -4.5V$ )

### ■ Maximum absolute ratings

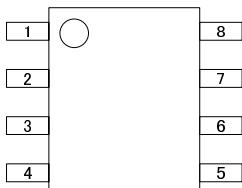
Parameter	Symbol	Limit	Unit	Note
Drain-source voltage	$V_{ds}$	-40	V	
Gate-source voltage	$V_{gs}$	$\pm 20$	V	
Continuous drain current <small>T<sub>a</sub>=25°C</small>	$I_d$	-6.5	A	1
		-5.0		
Pulsed drain current	$I_{dm}$	-20	A	2
Power dissipation <small>T<sub>a</sub>=25°C</small>	$P_d$	3.1	W	1
		2.0		
Junction and storage temperature range	$T_j, T_{stg}$	-55 to 150	°C	

### ■ Thermal characteristics

Parameter	Symbol	Typ.	Max.	Unit	Note
Maximum junction-to-ambient	$R_{\theta ja}$	24	40	°C/W	1
Maximum junction-to-ambient		54	75	°C/W	
Maximum junction-to-lead	$R_{\theta jl}$	21	30	°C/W	3

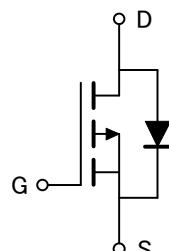
### ■ Pin configuration

SOP-8 (TOP VIEW)



Pin No.	Pin name
1	SOURCE
2	SOURCE
3	SOURCE
4	GATE
5	DRAIN
6	DRAIN
7	DRAIN
8	DRAIN

### ■ Circuit



# Single P-channel MOSFET

## ELM14443AA-N

### ■ Electrical characteristics

$T_a=25^\circ C$

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
<b>STATIC PARAMETERS</b>						
Drain-source breakdown voltage	BVdss	$Id=-250\ \mu A, Vgs=0V$	-40			V
Zero gate voltage drain current	Idss	$Vds=-32V$ $Vgs=0V$			-1 -5	$\mu A$
Gate-body leakage current	Igss	$Vds=0V, Vgs=\pm 20V$			$\pm 100$	nA
Gate threshold voltage	Vgs(th)	$Vds=Vgs, Id=-250\ \mu A$	-1.0	-1.9	-3.0	V
On state drain current	Id(on)	$Vgs=-10V, Vds=-5V$	-20			A
Static drain-source on-resistance	Rds(on)	$Vgs=-10V$ $Id=-6A$ $Vgs=-4.5V, Id=-5A$		33.3 54.0 48.0	42.0 68.0 63.0	$m\Omega$
Forward transconductance	Gfs	$Vds=-5V, Id=-6A$		14		S
Diode forward voltage	Vsd	$Is=-1A, Vgs=0V$		-0.75	-1.00	V
Max. body-diode continuous current	Is				-6	A
<b>DYNAMIC PARAMETERS</b>						
Input capacitance	Ciss	$Vgs=0V, Vds=-20V, f=1MHz$		657		pF
Output capacitance	Coss			143		pF
Reverse transfer capacitance	Crss			63		pF
Gate resistance	Rg	$Vgs=0V, Vds=0V, f=1MHz$		6.5		$\Omega$
<b>SWITCHING PARAMETERS</b>						
Total gate charge (10V)	Qg	$Vgs=-10V, Vds=-20V, Id=-6A$		14.2		nC
Total gate charge (4.5V)	Qg			7.1		nC
Gate-source charge	Qgs			2.2		nC
Gate-drain charge	Qgd			4.1		nC
Turn-on delay time	td(on)	$Vgs=-10V, Vds=-20V$ $RI=3.7\ \Omega, Rgen=3\ \Omega$		7.7		ns
Turn-on rise time	tr			8.0		ns
Turn-off delay time	td(off)			26.5		ns
Turn-off fall time	tf			11.5		ns
Body diode reverse recovery time	trr	$If=-6A, dl/dt=100A/\mu s$		21.9		ns
Body diode reverse recovery charge	Qrr	$If=-6A, dl/dt=100A/\mu s$		14.9		nC

### NOTE :

1. The value of  $R_{\theta ja}$  is measured with the device mounted on 1in<sup>2</sup> FR-4 board of 2oz. Copper, in still air environment with  $T_a=25^\circ C$ . The value in any given applications depends on the user's specific board design, The current rating is based on the  $t \leq 10s$  thermal resistance rating.
2. Repetitive rating, pulse width limited by junction temperature.
3. The  $R_{\theta ja}$  is the sum of the thermal impedance from junction to lead  $R_{\theta jl}$  and lead to ambient.
4. The static characteristics in Figures 1 to 6 are obtained using 80 $\mu s$  pulses, duty cycle 0.5%max.
5. These tests are performed with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_a=25^\circ C$ . The SOA curve provides a single pulse rating.



# Single P-channel MOSFET

ELM14443AA-N

## ■ Typical electrical and thermal characteristics

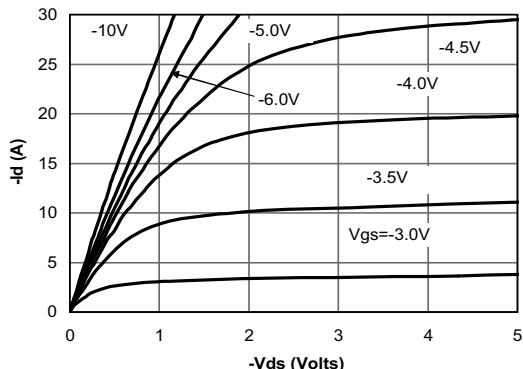


Fig 1: On-Region Characteristics

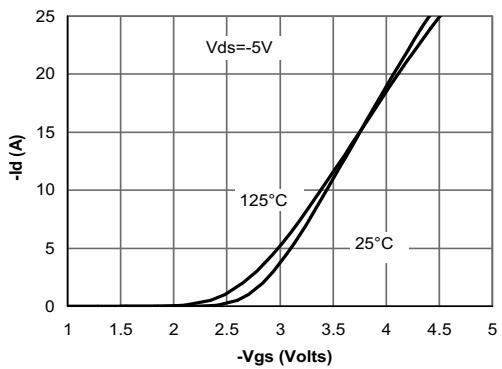


Figure 2: Transfer Characteristics

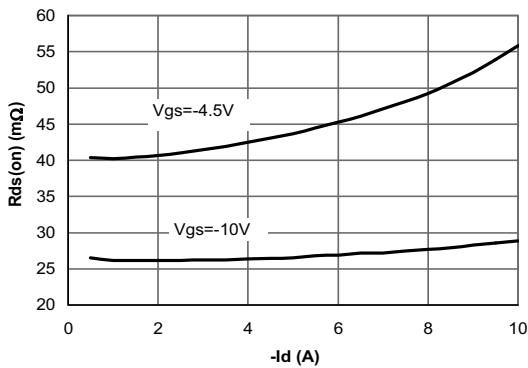


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

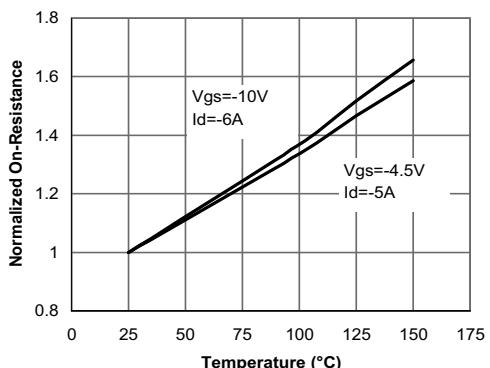


Figure 4: On-Resistance vs. Junction Temperature

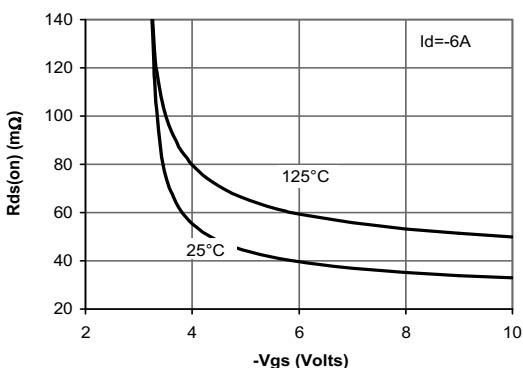


Figure 5: On-Resistance vs. Gate-Source Voltage

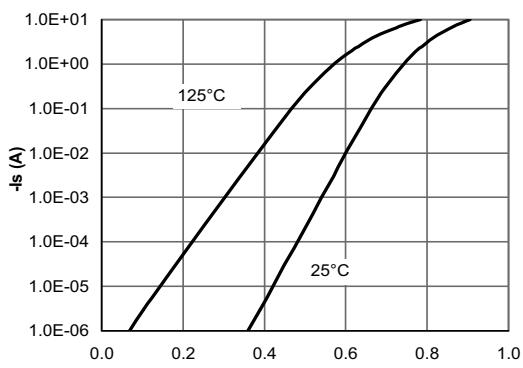


Figure 6: Body-Diode Characteristics

# Single P-channel MOSFET

ELM14443AA-N

